

# Fast Recovery Epitaxial Diode (FRED)

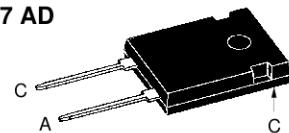
**DSEI 60**

**I<sub>FAVM</sub> = 60 A**  
**V<sub>RRM</sub> = 600 V**  
**t<sub>rr</sub> = 35 ns**

V <sub>RSM</sub>	V <sub>RRM</sub>	Type
V	V	
600	600	DSEI 60-06A



**TO-247 AD**



A = Anode, C = Cathode

Symbol	Test Conditions		Maximum Ratings	
I <sub>FRMS</sub>	T <sub>VJ</sub> = T <sub>VJM</sub>		100	A
I <sub>FAVM</sub> ①	T <sub>C</sub> = 70°C; rectangular, d = 0.5		60	A
I <sub>FRM</sub>	t <sub>p</sub> < 10 µs; rep. rating, pulse width limited by T <sub>VJM</sub>		800	A
I <sub>FSM</sub>	T <sub>VJ</sub> = 45°C; t = 10 ms (50 Hz), sine		550	A
	t = 8.3 ms (60 Hz), sine		600	A
	T <sub>VJ</sub> = 150°C; t = 10 ms (50 Hz), sine		480	A
	t = 8.3 ms (60 Hz), sine		520	A
I <sup>2</sup> t	T <sub>VJ</sub> = 45°C	t = 10 ms (50 Hz), sine	1510	A <sup>2</sup> s
		t = 8.3 ms (60 Hz), sine	1490	A <sup>2</sup> s
	T <sub>VJ</sub> = 150°C; t = 10 ms (50 Hz), sine		1150	A <sup>2</sup> s
		t = 8.3 ms (60 Hz), sine	1120	A <sup>2</sup> s
T <sub>VJ</sub>			-40...+150	°C
T <sub>VJM</sub>			150	°C
T <sub>stg</sub>			-40...+150	°C
P <sub>tot</sub>	T <sub>C</sub> = 25°C		166	W
M <sub>d</sub>	Mounting torque		0.8...1.2	Nm
Weight			6	g

Symbol	Test Conditions		Characteristic Values	
	typ.		max.	
I <sub>R</sub>	T <sub>VJ</sub> = 25°C	V <sub>R</sub> = V <sub>RRM</sub>	200	µA
	T <sub>VJ</sub> = 25°C	V <sub>R</sub> = 0.8 • V <sub>RRM</sub>	100	µA
	T <sub>VJ</sub> = 125°C	V <sub>R</sub> = 0.8 • V <sub>RRM</sub>	14	mA
V <sub>F</sub>	I <sub>F</sub> = 70 A;	T <sub>VJ</sub> = 150°C	1.5	V
		T <sub>VJ</sub> = 25°C	1.8	V
V <sub>T0</sub>	For power-loss calculations only		1.13	V
r <sub>T</sub>	T <sub>VJ</sub> = T <sub>VJM</sub>		4.7	mΩ
R <sub>thJC</sub>			0.75	K/W
R <sub>thCK</sub>			35	K/W
R <sub>thJA</sub>			2.25	K/W
t <sub>rr</sub>	I <sub>F</sub> = 1 A; -di/dt = 200 A/µs; V <sub>R</sub> = 30 V; T <sub>VJ</sub> = 25°C		35	ns
I <sub>RM</sub>	V <sub>R</sub> = 350 V; I <sub>F</sub> = 60 A; -di <sub>F</sub> /dt = 480 A/µs	L ≤ 0.05 µH; T <sub>VJ</sub> = 100°C	19	21
				A

① I<sub>FAVM</sub> rating includes reverse blocking losses at T<sub>VJM</sub>, V<sub>R</sub> = 0.8 V<sub>RRM</sub>, duty cycle d = 0.5

Data according to IEC 60747

IXYS reserves the right to change limits, test conditions and dimensions

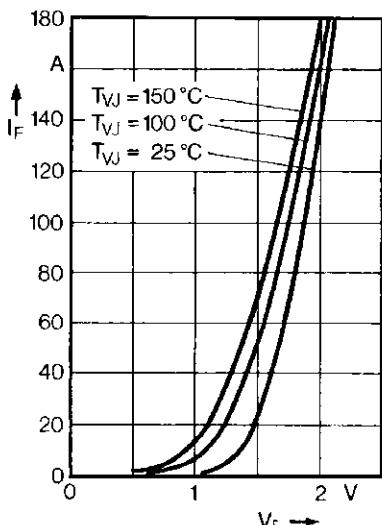


Fig. 1 Forward current versus voltage drop.

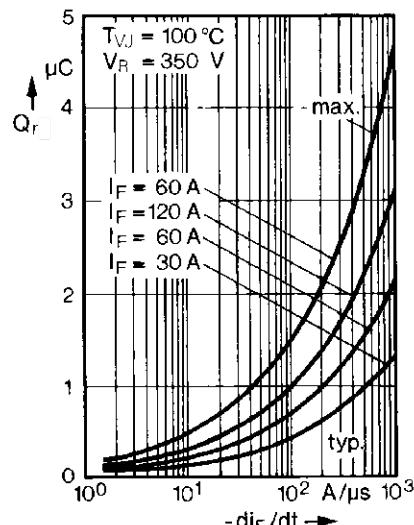


Fig. 2 Recovery charge versus  $-di_F/dt$ .

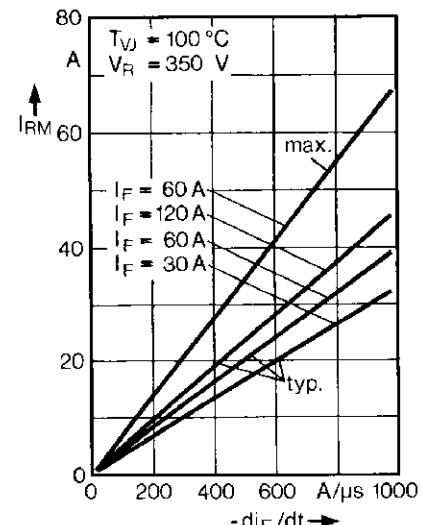


Fig. 3 Peak reverse current versus  $-di_F/dt$ .

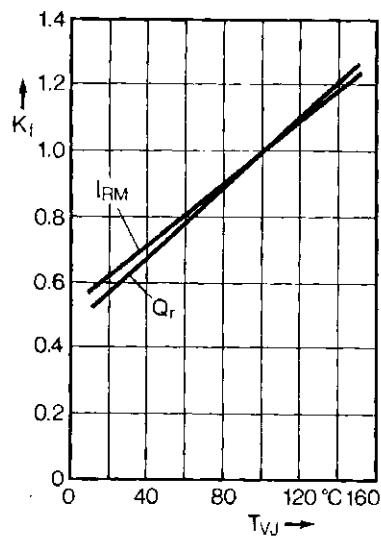


Fig. 4 Dynamic parameters versus junction temperature.

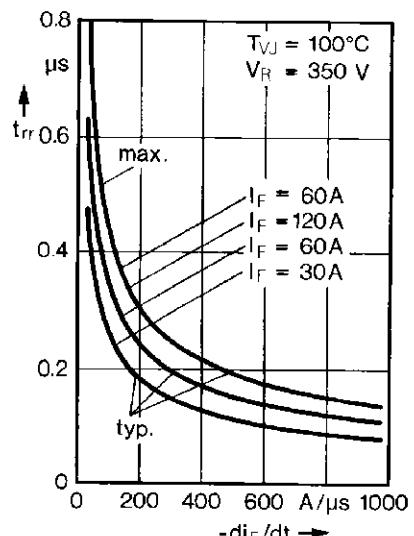


Fig. 5 Recovery time versus  $-di_F/dt$ .

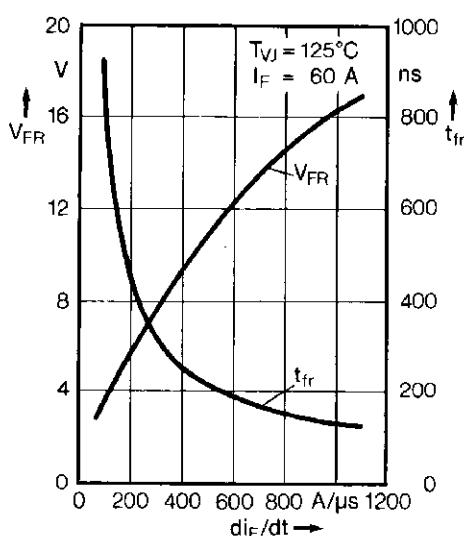


Fig. 6 Peak forward voltage versus  $di_F/dt$ .

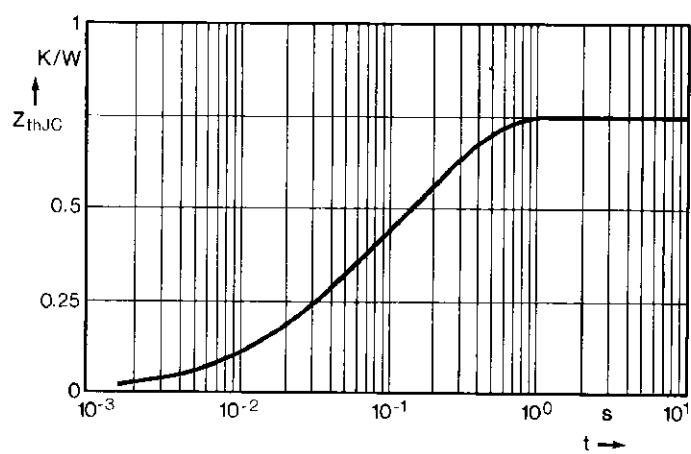
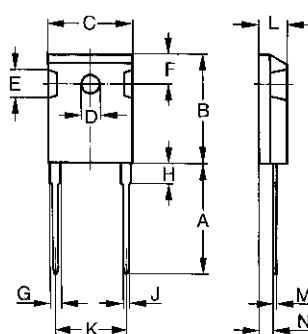


Fig. 7 Transient thermal impedance junction to case.

### Dimensions



Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	19.81	20.32	0.780	0.800
B	20.80	21.46	0.819	0.845
C	15.75	16.26	0.610	0.640
D	3.55	3.65	0.140	0.144
E	4.32	5.49	0.170	0.216
F	5.4	6.2	0.212	0.244
G	1.65	2.13	0.065	0.084
H	-	4.5	-	0.177
J	1.0	1.4	0.040	0.055
K	10.8	11.0	0.426	0.433
L	4.7	5.3	0.185	0.209
M	0.4	0.8	0.016	0.031
N	2.2	2.54	0.087	0.102